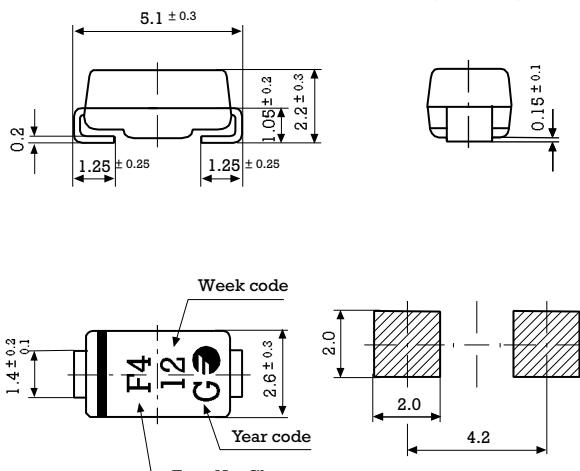


1 Amp. Surface Mounted Schottky Barrier Rectifier

Dimensions in mm. 	CASE: SMA/DO-214AC (Plastic)	Voltage 20 V to 60 V	Current 1.0 A
<ul style="list-style-type: none"> • Metal Silicon Junction, majority carrier conduction • High current capability, low forward voltage drop • Guardring for overvoltage protection • Low power loss, high efficiency • High surge capability • Plastic material carries U/L recognition 94 VO • Low profile package • Easy pick and place 			

Maximum Ratings, according to IEC publication No. 134

		FSS12	FSS13	FSS14	FSS15	FSS16
	Marking Code	A1	A2	A3	A4	A5
V_{RPM}	Peak recurrent reverse voltage (V)	20	30	40	50	60
V_{RMS}	Maximum RMS voltage (V)	14	21	28	35	42
V_{DC}	Maximum DC blocking voltage (V)	20	30	40	50	60
$I_F(AV)$	Maximum average Forward current.			1 A		
I_{FSM}	8.3 ms. peak forward surge current (Jedec Method)			40 A		
T_j	Operating temperature range	– 65 to + 125 °C		– 65 to + 150 °C		
T_{stg}	Storage temperature range	– 65 to + 150 °C				

Electrical Characteristics at Tamb = 25 °C

V_F	Max. forward voltage drop at $I_F = 1.0 \text{ A}$	0.55 V	0.75 V
I_R	Max. Instantaneous reverse Ta = 25 °C current at V_{RPM}	0.5 mA	
	Ta = 100 °C	10 mA	5 mA
R_{thj-a} R_{thj-l}		88 °C/W 28 °C/W	

NOTE: Thermal Resistance from junction to lead or to ambient PCB mounted with 5x5 mm copper pads areas.

